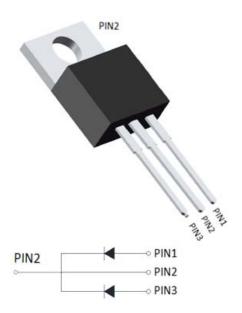




Ultra-Fast Recovery Rectifier Diodes



Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Adopt GPP chip
- Passivation for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1010CT- B1-0000S	MUR1015CT- B1-0000S	MUR1020CT- B1-0000S	MUR1040CT- B1-0000S	MUR1060CT- B1-0000S
Device marking code			MUR1010CT	MUR1015CT	MUR1020CT	MUR1040CT	MUR1060CT
Repetitive Peak Reverse Voltage	VRRM	٧	100	150	200	400	600
Average Rectified Output Current @60Hz half sine-wave, R-load, Tc(FIG.1)	lo	Α	10				
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25℃	IFSM	Α	75				
Current Squared Time @1ms≤t<8.3ms Tj=25°C, Rating of per diode	l ² t	A ² s	23				
Storage Temperature	T _{stg}	$^{\circ}$	-55 ~ +150				
Junction Temperature	Tj	$^{\circ}$	-55 ~ +1 50				

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

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PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MUR1010CT- B1-0000S	MUR1015CT- B1-0000S	MUR1020CT- B1-0000S	MUR1040CT- B1-0000S	MUR1060CT- B1-0000S
Maximum instantaneous forward voltage drop per diode	VFM	٧	IFM=5.0A		0.975		1.3	1.5
Maximum DC reverse current at	IRRM1		VRM=VRRM T _a =25°C	10				
rated DC blocking voltage per diode	IRRM2	uA	VRM=VRRM T _a =125℃	500				
Reverse Recovery Time Trr ns		I _F =0.5A I _{RM} =1A I _{RR} =0.25A	50					

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

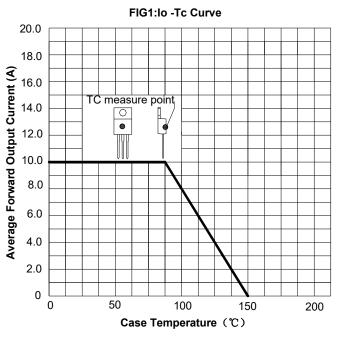
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PARAMETER		SYMBOL	UNIT	MUR1010CT- B1-0000S	MUR1015CT- B1-0000S	MUR1020CT- B1-0000S	MUR1040CT- B1-0000S	MUR1060CT- B1-0000S	
	Thermal Resistance	Between junction and case	$R_{\theta J-C}$	°C/W			2.0		

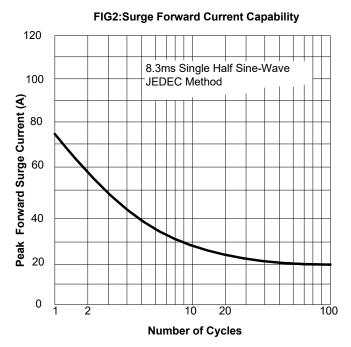


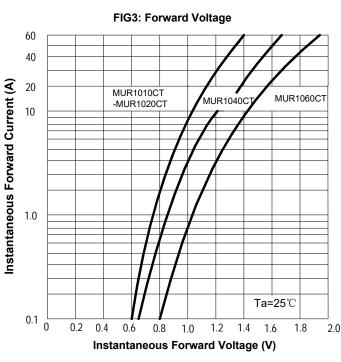
■Ordering Information (Example)

PREFERED P/N			UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE		
MUR1010CT- B1-0000S	MUR1015CT -B1-0000S	MUR1020CT- B1-0000S	MUR1040CT- B1-0000S	MUR1060CT- B1-0000S	Approximate 1.87	50	1000	5000	Tube

■Characteristics (Typical)







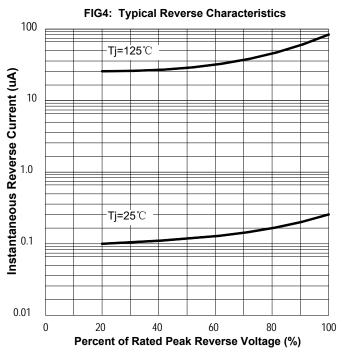
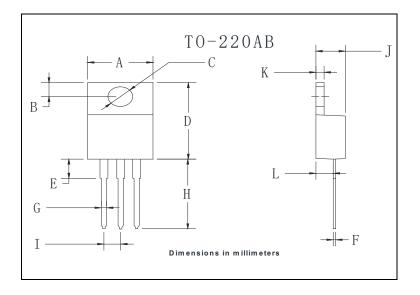


FIG.5 Diagram of circuit and Testing wave form of reverse recovery time

■Outline Dimensions



TO-220AB						
Dim	Min	Max				
Α	9.5	10.9				
В	2.22	3.27				
С	3.34	4.31				
D	14.5	15.5				
Е	3.16	4.46				
F	0.28	0.64				
G	0.68	0.94				
Н	13.06	14.62				
I	2.01	3.07				
J	4.04	5.1				
K	1.14	1.4				
L	2.14	3.19				



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